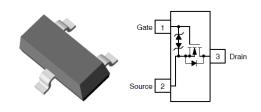
# 2N7002B

**N-Channel Enhancement Mode MOSFET** 

# **High Speed Switching Application**

#### **Features**

- ESD rating: 2000V (HBM)
- Low On-Resistance:  $R_{DS(on)} < 3\Omega$  @  $V_{GS} = 10V$
- High power and current handling capability
- · Very fast switching
- · RoHS compliant device



**SOT-23** 

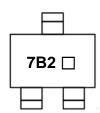
### **Applications**

• High speed line driver

### **Ordering Information**

Part Number	Marking Code	Package	Packaging
2N7002B	7B2 □	SOT-23	Tape & Reel

### **Marking Information**



**7B2 = Specific Device Code** 

☐ = Year & Week Code Marking

### **Absolute Maximum Ratings** (T<sub>amb</sub>=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Drain-Source voltage	V <sub>DS</sub>	60	V
Gate-Source voltage	V <sub>GS</sub>	±20	V
Maximum drain current (Note 1)	I <sub>D</sub>	300	mA
Pulsed drain current (Note 1)	I <sub>DP</sub>	800	mA
Power dissipation (Note 2)	P <sub>D</sub>	350	mW
Operating junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55 ~ 150	°C
Thermal resistance junction to ambient (Note 2)	R <sub>th(j-a)</sub>	350	°C/W

Note 1) Limited only maximum junction temperature

Note 2) Device mounted on FR-4 board with recommended pad layout.

# **Electrical Characteristics** (T<sub>amb</sub>=25°C, Unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Drian-Source breakdown voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0	60	-	-	V
Gate-Source breakdown voltage	BV <sub>GSS</sub>	I <sub>G</sub> =250μA, V <sub>DS</sub> =0	±20	-	-	V
Gate-Threshold voltage	$V_{GS(th)}$	I <sub>D</sub> =250uA, V <sub>DS</sub> =V <sub>GS</sub>	1	-	2.5	V
Zero Gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0	-	-	1	μΑ
	I <sub>GSS</sub>	$V_{GS}=\pm5V$ , $V_{DS}=0V$	-	-	±100	nA
Gate-body leakage		V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V			±450	nA
		V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±10	μΑ
Drain-Source on-resistance (Note 3)	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	-	-	3	Ω
		V <sub>GS</sub> =5V, I <sub>D</sub> =0.05A	-	-	3.5	
Forward trans-conductance (Note 3)	g <sub>fs</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =0.2A	0.08	-	-	S
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0, f=1MHz	-	30	50	pF
Output capacitance	C <sub>oss</sub>		-	7	-	
Reverse Transfer capacitance	C <sub>rss</sub>		-	4	-	
Turn-on delay time (Note 3, 4)	t <sub>d(on)</sub>		-	2	-	
Rise time (Note 3, 4)	t <sub>r</sub>	V <sub>DD</sub> =30V, I <sub>D</sub> =0.2A,	-	15	-	ns
Turn-off delay time (Note 3, 4)	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =10 $\Omega$		8	-	
Fall time (Note 3, 4)	t <sub>f</sub>		-	11	-	
Total gate charge (Note 3, 4)	$Q_g$		-	0.6	0.8	
Gate-Source charge (Note 3, 4)	$Q_gs$	$V_{DS}$ =10V, $I_{D}$ =0.25A, $V_{GS}$ =4.5V	-	0.2	-	nC
Gate-Drain charge (Note 3, 4)	$Q_{gd}$		-	0.2	-	
Diode forward voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =0.2A	-	-	1.3	V

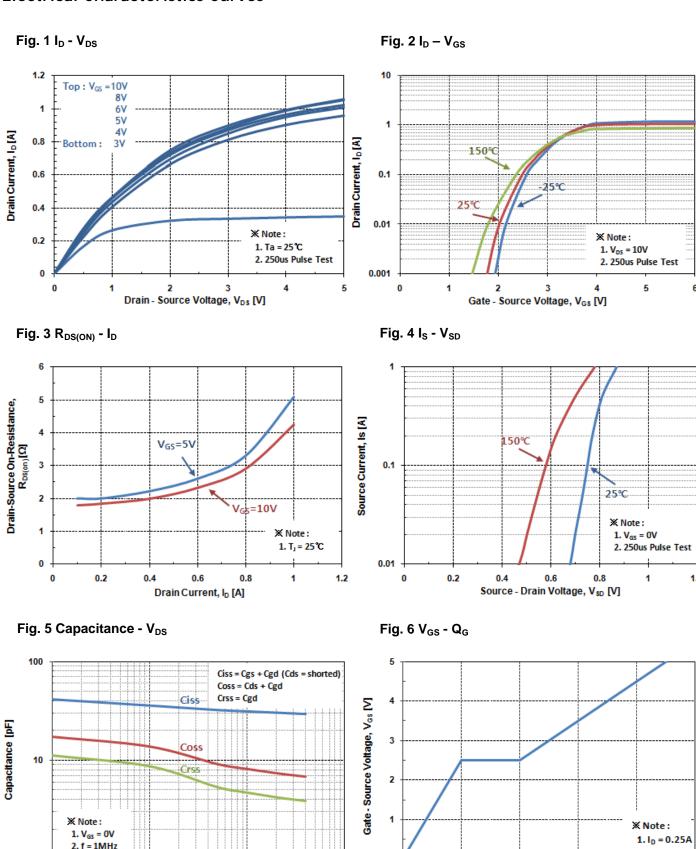
 $<sup>^{\</sup>text{Note 3})}$  Pulse test: Pulse width $\leq$ 300us, Duty cycle $\leq$ 2%

 $<sup>^{\</sup>mbox{\scriptsize Note 4})}$  Essentially independent of operating temperature typical characteristics.

#### **Electrical Characteristics Curves**

0.1

Drain - Source Voltage, VDS [V]



0

0.2

0.4

Drain - Source Voltage, V<sub>D8</sub> [V]

0.6

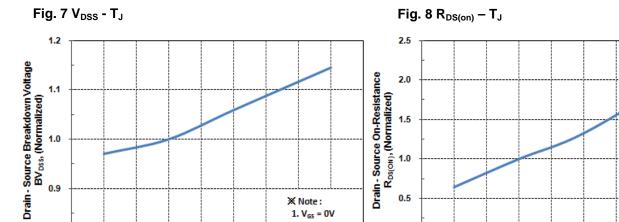
1. V<sub>GS</sub> = 10V

2. I<sub>D</sub> = 0.5A

125

150

175



2. I<sub>D</sub> = 250uA

125

150

0.8

-50

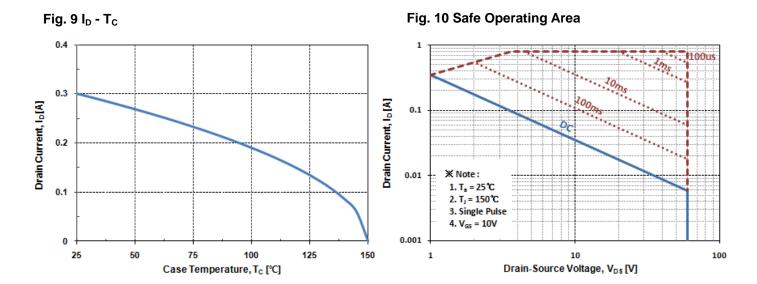
-25

25

50

Junction Temperature, T<sub>J</sub> [℃]

75



0.0

-50

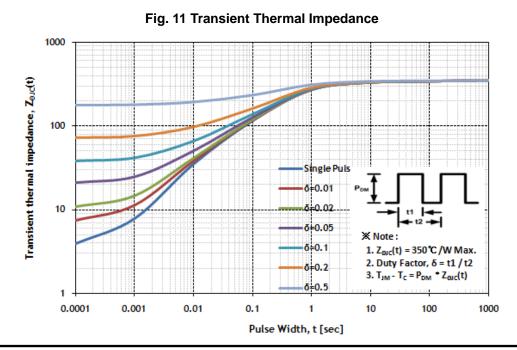
-25

25

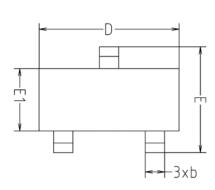
75

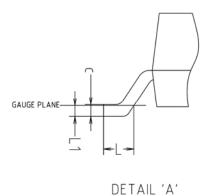
50

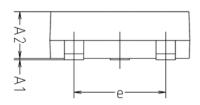
Junction Temperature, T<sub>J</sub> [℃]

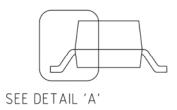


# **Package Outline Dimensions**



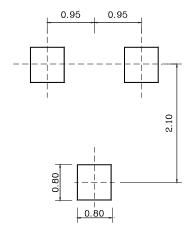






SYMBOL	MILLIMETERS			NOTE	
STILLOCE	MINIMUM	NOMINAL	MAXIMUM	NOTE	
A1	0.00	-	0.10		
A2	0.82	-	1.02		
Ь	0.39	0.42	0.45		
С	0.09	0.12	0.15		
D	2.80	2.90	3.00		
Е	2.20	2.40	2.60		
E1	1.20	1.30	1.40		
е	1.90BSC				
L	0.20	-	-		
L1	0.12BSC				

#### **X Recommend PCB solder land (Unit: mm)**



2N7002B

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